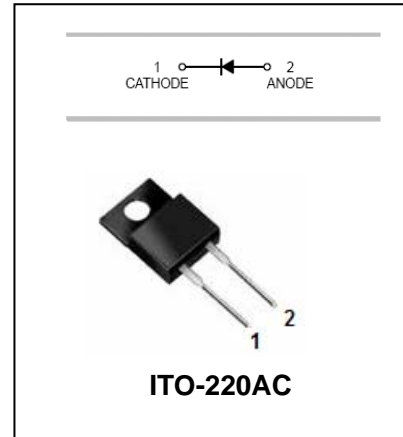


Schottky Barrier Rectifiers

MBRF3030---MBRF30100

FEATURES

- High surge capacity.
- For use in low voltage,high frequency Inverters,free wheeling,and polarity protection applications.
- Metal silicon junction,majority carrier conduction.
- High current capacity,lowforward voltage drop.
- Guard ring for over voltage protection.



MAXIMUM RATING operating temperature range applies unless otherwise specified

Symbol	Parameter	MBRF 3030	MBRF 3035	MBRF 3040	MBRF 3045	MBRF 3050	MBRF 3060	MBRF 3080	MBRF 30100	Unit
V_{RRM}	Recurrent Peak Reverse Voltage	30	35	40	45	50	60	80	100	V
V_{RMS}	RMS Voltage	21	25	28	32	35	42	56	70	V
V_{DC}	DC Blocking Voltage	30	35	40	45	50	60	80	100	V
$I_{F(AV)}$	Average Forward Total Device Rectified Current @ $T_A=100^{\circ}C$	30								A
I_{FSM}	Peak Forward Surge Current 8.3ms Single Half Sine-wave Superimposed on rated load	300								A
$R_{\theta JC}$	Thermal Resistance(Note1)	4.4								$^{\circ}C/W$
$T_j T_{stg}$	Operating Junction and Storage Temperature Range	-55 to +150								$^{\circ}C$

Note:1.Thermal resistance from junction to case.



Schottky Barrier Rectifiers

MBRF3030---MBRF30100

ELECTRICAL CHARACTERISTICS @ $T_a=25^{\circ}\text{C}$ unless otherwise specified

Parameter	Symbol	Test conditions	MBRF3030- MBRF3045	MBRF3050- MBRF3060	MBRF3080- MBRF30100	UNIT
			MAX			
Reverse Current	I_R	$V_R=V_{RRM}, T_A=25^{\circ}\text{C}$	0.1	0.1	0.1	mA
		$V_R=V_{RRM}, T_A=125^{\circ}\text{C}$	15	25	50	
Forward Voltage	V_F (Note1)	$I_F=30\text{A}, T_A=25^{\circ}\text{C}$	0.70	0.8	0.85	V
		$I_F=30\text{A}, T_A=125^{\circ}\text{C}$	0.57	0.7	0.65	

Note:1.Pulse test:300µs width,1% duty cycle

PACKAGE OUTLINE

Plastic surface mounted package

ITO-220AC

ITO-220AC		
Dim	Min	Max
A	9.90	10.30
B	14.80	15.20
C	4.50 Typical	
D	2.70 Typical	
E	2.80	3.20
F	13.00	13.40
G	3.2 Typical	
H	28.00	28.40
J	0.60 Typical	
L	0.50	0.75
M	1.40 Typical	
N	2.90	3.10
P	5.00	5.20
R	1.20 Typical	
All Dimensions in mm		